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PHOTOMULTIPLIER TUBES R7518 R7518P (For Photon Counting)

High Sensitivity with Low Noise Photocathode

FEATURES

Spectral Response	185 nm to 730 nm
●High Cathode Sensitivity	
Luminous	130 μ A/lm
Radiant at 410 nm	85 mA/W
●High Anode Sensitivity (at 1000 V)	
Luminous	1560 A/lm
Radiant at 410 nm	$10.2 \times 10^5 \text{A/W}$
●Low Dark Current	0.2 nA
●Low Dark Counts (R7518P)	10 s ⁻¹

APPLICATIONS

- Chemiluminescence Detection
- **●**Bioluminescence Detection
- ●Fluorescence Spectrometer
- ●SO₂ Monitor (UV Fluorescence)



SPECIFICATIONS

GENERAL

Parameter		Description/Value					
Spectral Response		185 to 730	nm				
Wavelength of Maximur	n Response	410	nm				
Photocathode	Material	Low noise bialkali					
Filolocatilode	Minimum Effective Area	8 × 24	mm				
Window Material		UV glass	_				
	Secondary Emitting Surface	Low noise bialkali	_				
Dynode	Structure	Circular-cage	_				
	Number of Stages	9	_				
Direct Interelectrode	Anode to Last Dynode	4	pF				
Capacitances	Anode to All Other Electrode	6	pF				
Base		11-pin base JEDEC No. B11-88	_				
Weight		45	g				
Operating Ambient Tem	perature	-30 to +50	°C				
Storage Temperature		-30 to +50	°C				
Suitable Socket		E678-11A (Sold Separately)	_				
Suitable Socket Assem	bly	E717-63 (Sold Separately)	_				

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MAXIMUM RATINGS (Absolute Maximum Values)

Parameter		Value					
Cupply Voltage	Between Anode and Cathode	1250	V				
Supply Voltage	Between Anode and Last Dynode	250	V				
Average Anode Curr	rent ^A	0.1	mΑ				

CHARACTERISTICS (at 25 °C)

Parameter		R7518 fc	or General	Purpose	R7518P f	Unit		
		Min.	Тур.	Max.	Min.	Тур.	Max.	Oilit
	Quantum Efficiency at 300 nm (Peak)	_	29	_	_	29	_	%
Cathode Sensitivity	Luminous ^B	120	130	_	120	130	_	μ A /lm
Callibue Selisitivity	Radiant at 410 nm (Peak)	_	85	_	_	85	_	mA/W
	Blue Sensitivity Index (CS 5-58)	_	10	_	_	10	_	μΑ/lm-b
Anode Sensitivity	Luminous ^C	1200	1560	_	1200	1560	_	A/lm
Arrode Sensitivity	Radiant at 400 nm	_	10.2×10^{5}	_	_	10.2×10^{5}	_	A/W
Gain ^D	Gain ^D		1.2×10^{7}	_	_	1.2×10^{7}	_	_
Anode Dark Current E	Anode Dark Current ^E (After 30 min Storage in darkness)		0.2	2.0	_	0.2	0.5	nA
Anode Dark Counts E		_	_	_	_	10	50	S ⁻¹
ENI (Equivalent Noise	ENI (Equivalent Noise Input) F		2.7×10^{-17}	_	_	2.7×10^{-17}	_	W
Time Response ^D	Anode Pulse Rise Time G	_	2.2	_	_	2.2	_	ns
	Electron Transit Time	_	22	_	_	22	_	ns
	Transit Time Spread (TTS) H	_	1.2	_	_	1.2	_	ns
Anode Current Stability J	Light Hysteresis	_	0.1	_	_	0.1	_	%
	Voltage Hysteresis	_	1.0	_	_	1.0	_	%

NOTES

- A: Averaged over any interval of 30 seconds maximum.
- B: The light source is a tungsten filament lamp operated at a distribution temperature of 2856 K. Supply voltage is 150 V between the cathode and all other electrodes connected together as anode.
- C: Measured with the same light source as Note B and with the anode-tocathode supply voltage and voltage distribution ratio shown in Table 1 below.
- D:Measured with the same supply voltage and voltage distribution ratio as Note E after removal of light.
- E: Measured at the voltage producing the gain of 1×10^6 .
- F: ENI is an indication of the photon-limited signal-to-noise ratio. It refers to the amount of light in watts to produce a signal-to-noise ratio of unity in the output of a photomultiplier tube.

$$ENI = \frac{\sqrt{2q \cdot ldb \cdot G \cdot f}}{S} \quad (W)$$

where $q = Electronic charge. (1.60 \times 10^{-19} coulomb)$

ldb = Anode dark current(after 30 minute storage) in amperes.

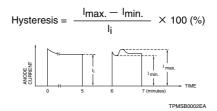
G = Gair

f = Bandwidth of the system in hertz. (usually 1 hertz)

S = Anode radiant sensitivity in amperes per watt at the wavelength of peak response

- G:The rise time is the time for the output pulse to rise from 10% to 90% of the peak amplitude when the entire photocathode is illuminated by a delta function light pulse.
- H:The electron transit time is the interval between the arrival of delta function light pulse at the entrance window of the tube and the time when the anode output reaches the peak amplitude. In measurement, the whole photocathode is illuminated.
- J: Also called transit time jitter. This is the fluctuation in electron transit time between individual pulses in the signal photoelectron mode, and may be defined as the FWHM of the frequency distribution of electron transit times.

K: Hysteresis is temporary instability in anode current after light and voltage are applied.



(1)Current Hysteresis

The tube is operated at 750 V with an anode current of 1 μ A for 5 minutes. The light is then removed from the tube for a minute. The tube is then re-illuminated by the previous light level for a minute to measure the variation. (2)Voltage Hysteresis

The tube is operated at 300 V with an anode current of 0.1 μ A for 5 minutes. The light is then removed from the tube and the supply voltage is quickly increased to 800 V. After a minute, the supply voltage is then reduced to the previous value and the tube is re-illuminated for a minute to measure the variation.

Table 1:Voltage Distribution Ratio

Electrodes	K	Dy.	D)	/2 D	уЗ	Dy4	D	y5	Dy6	Dy	y7	Dy8	D	у9		Р
Distribution Ratio		1	1	1		1	1	1	1	1	-	1	1		1	

Supply Voltage: 1000 V, K: Cathode, Dy: Dynode, P: Anode

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Figure 1: Typical Spectral Response

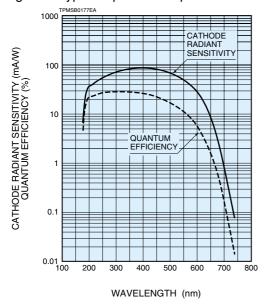


Figure 3: Typical Time Response

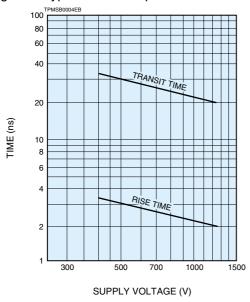


Figure 5: Typical Single Photon Pulse Height Distribution for R7518P

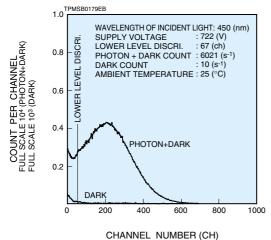


Figure 2: Typical Gain and Anode Dark Current

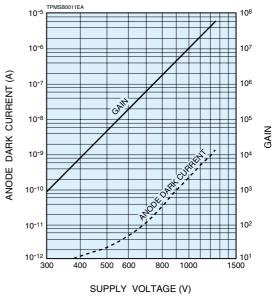


Figure 4: Typical ENI vs. Wavelength

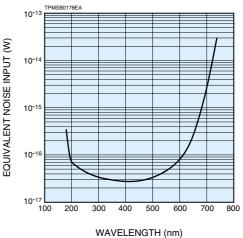
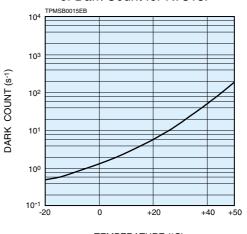


Figure 6: Typical Temperature Characteristics of Dark Count for R7518P



TEMPERATURE (°C)

PHOTOMULTIPLIER TUBES R7518, R7518P (For Photon Counting)

Figure 7: Dimensional Outline and Basing Diagram (Unit: mm)

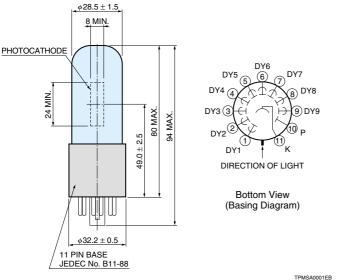
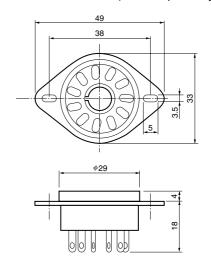
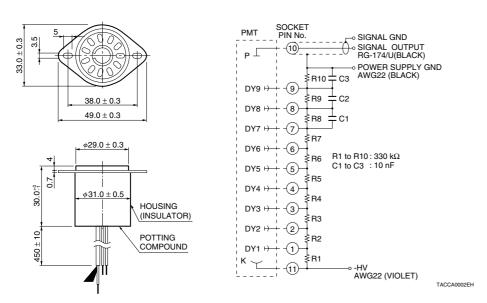


Figure 8: Socket E678-11A (Sold Separately)



TACCA0064EA

Figure 9: D Type Socket Assembly E717-63 (Sold Separately)



* Hamamatsu also provides C4900 series compact high voltage power supplies and C6270 series DP type socket assemblies which incorporate a DC to DC converter type high voltage power supply.

Warning-Personal Safety Hazards

Electrical Shock–Operating voltages applied to this device present a shock hazard.

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TPMS1060E02

APR. 2005. IP